NSN 5961-01-381-8328

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-381-8328 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Function For Which Designed:** Current regulator **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 limiting voltage **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset and 50.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 135.0 degrees celsius junction **Special Features:** N-channel jfet **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: